NSN 5962-01-356-9317

Memory Microcircuit - Page 1 of 1

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Features Provided:

Electrostatic sensitive and monolithic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Product Name:

Electrically programmable rom

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufacturee r standards, etc.).

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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